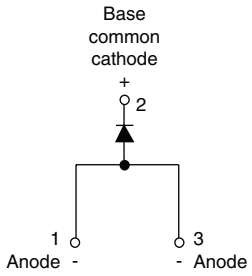
Fast Soft Recovery Rectifier Diode, 10 A

D²PAK (SMD-220)



FEATURES/DESCRIPTION

The 10ETF..S fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This product series has been designed and qualified for industrial level.

PRODUCT SUMMARY	
V_F at 10 A	< 1.33 V
t_{rr}	80 ns
V_{RRM}	1000/1200 V

APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Sinusoidal waveform	10	A
V_{RRM}		1000/1200	V
I_{FSM}		160	A
V_F	10 A, T_J = 25 °C	1.33	V
t_{rr}	1 A, 100 A/µs	80	ns
T_J	Range	- 40 to 150	°C

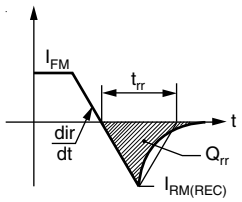
VOLTAGE RATINGS			
PART NUMBER	V_{RRM}, MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 °C mA
10ETF10S	1000	1100	4
10ETF12S	1200	1300	

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	T_C = 125 °C, 180° conduction half sine wave	10	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	160	A
		10 ms sine pulse, no voltage reapplied	185	A
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	128	A^2s
		10 ms sine pulse, no voltage reapplied	180	A^2s
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reapplied	1800	$A^2\sqrt{s}$

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	10 A, T_J = 25 °C		1.33	V
Forward slope resistance	r_t	T_J = 150 °C		22.9	mΩ
Threshold voltage	$V_{F(TO)}$			0.96	V
Maximum reverse leakage current	I_{RM}	T_J = 25 °C	V_R = Rated V_{RRM}	0.1	mA
		T_J = 150 °C		4	

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Reverse recovery time	t_{rr}	I_F at 10 Apk 25 A/µs 25 °C	310	ns	
Reverse recovery current	I_{rr}		4.7	A	
Reverse recovery charge	Q_{rr}		1.05	µC	
Typical snap factor	S		0.6		

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	1.5	°C/W
Maximum thermal resistance, junction to ambient (PCB mount)	R_{thJA} (1)		62	
Soldering temperature	T_S		240	°C
Approximate weight			2	g
			0.07	oz.
Marking device		Case style D^2PAK (SMD-220)	10ETF10S	
			10ETF12S	

Note

(1) When mounted on 1" square (650 mm^2) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W
For recommended footprint and soldering techniques refer to application note #AN-994

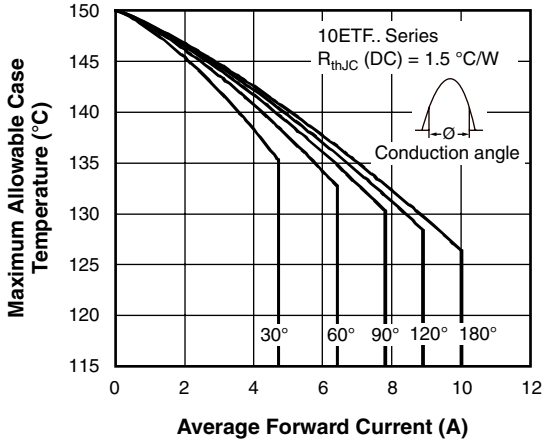


Fig. 1 - Current Rating Characteristics

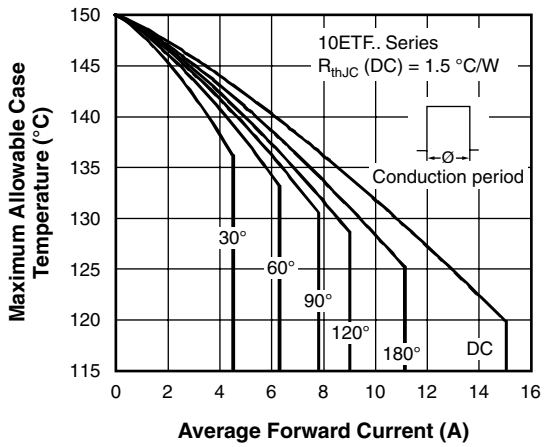


Fig. 2 - Current Rating Characteristics

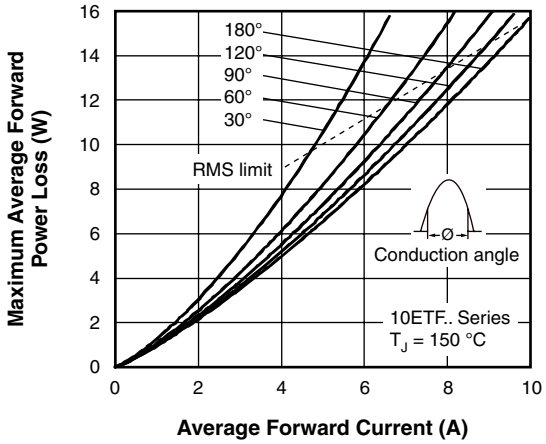


Fig. 3 - Forward Power Loss Characteristics

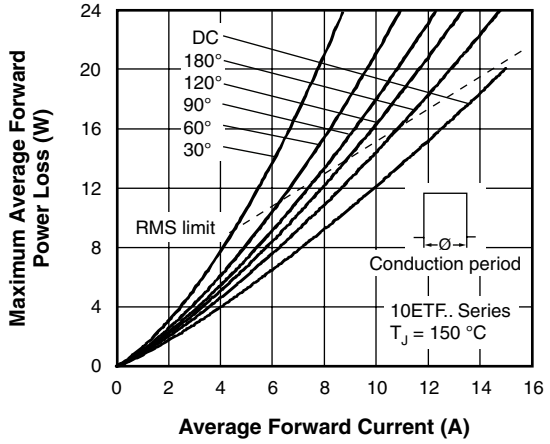


Fig. 4 - Forward Power Loss Characteristics

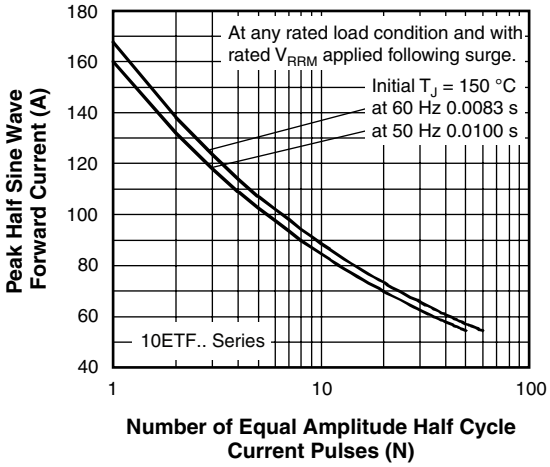


Fig. 5 - Maximum Non-Repetitive Surge Current

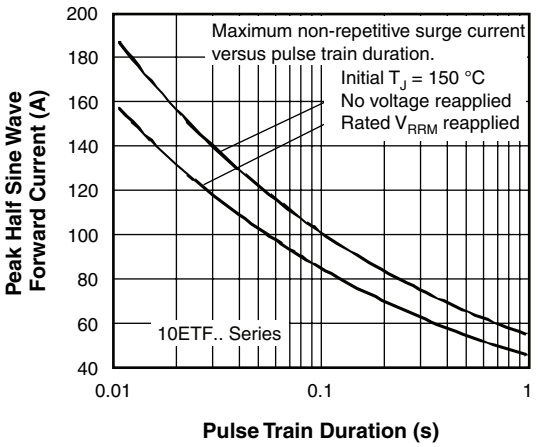


Fig. 6 - Maximum Non-Repetitive Surge Current

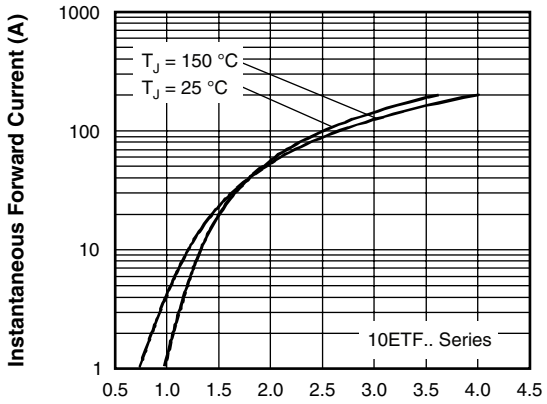


Fig. 7 - Forward Voltage Drop Characteristics

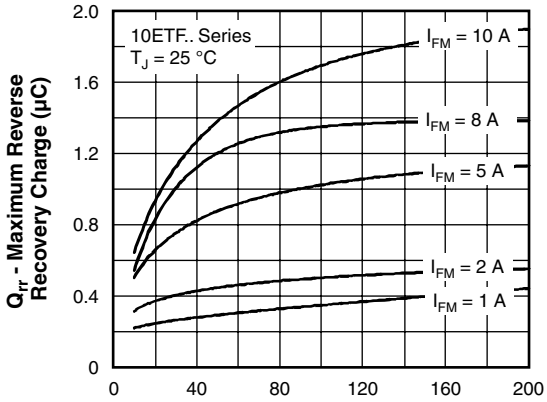


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

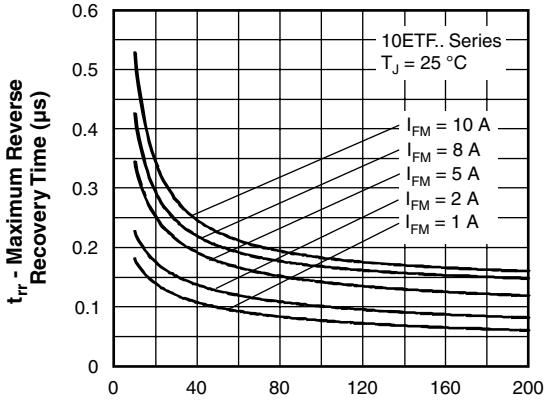


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

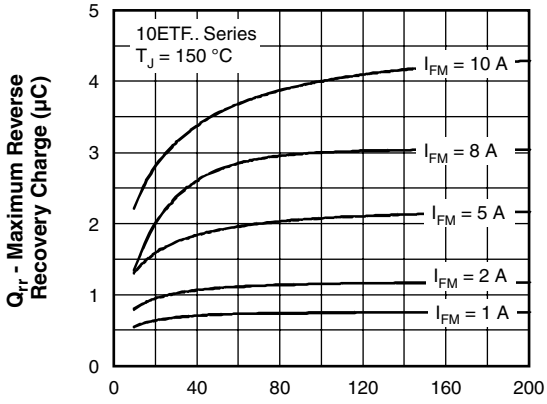


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

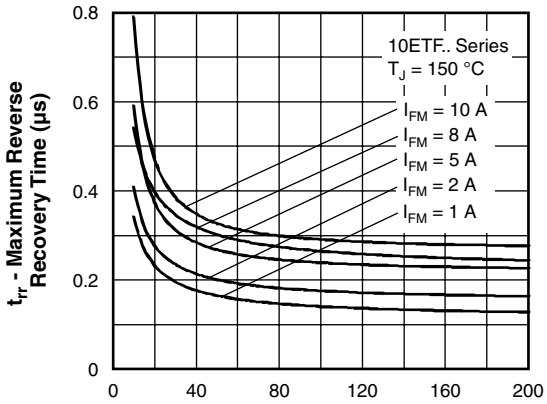


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

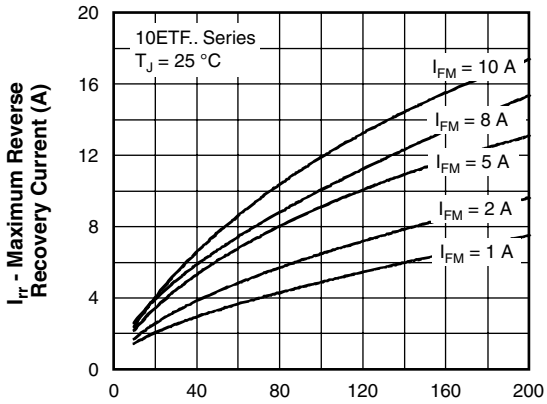


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

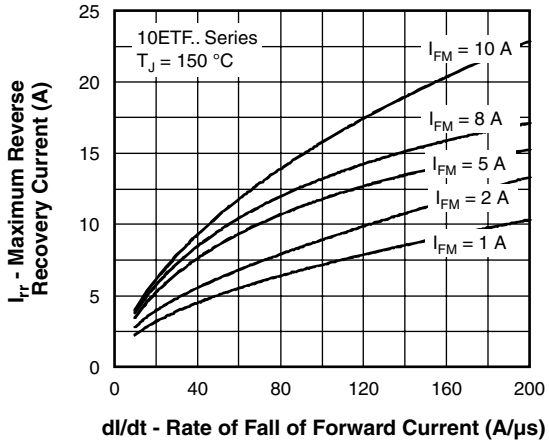


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

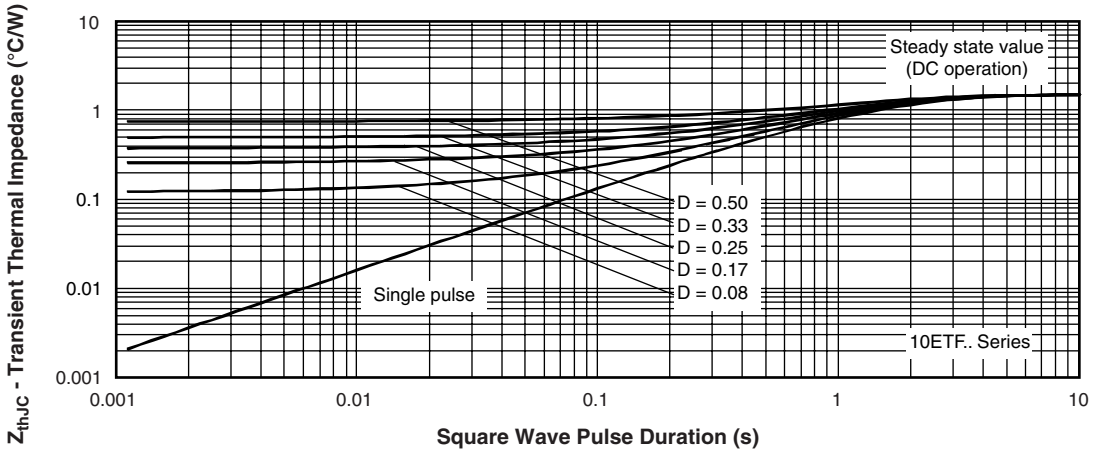


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code

10	E	T	F	12	S	TRL	-
1	2	3	4	5	6	7	8

1 - Current rating (10 = 10 A)

2 - Circuit configuration:
E = Single diode

3 - Package:
T = D^2PAK (TO-220AC)

4 - Type of silicon:
F = Fast soft recovery rectifier

5 - Voltage code x 100 = V_{RRM} (10 = 1000 V, 12 = 1200 V)

6 - S = Surface mountable

7 - • None = Tube
• TRR = Tape and reel (right oriented)
• TRL = Tape and reel (left oriented)

8 - • None = Standard production
• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95046
Part marking information	http://www.vishay.com/doc?95054
Packaging information	http://www.vishay.com/doc?95032

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